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TOSHIBA PHOTOCOUPLER PHOTO RELAY

T L P 3 1 3 0

MEASUREMENT INSTRUMENTS LOGIC IC TESTERS / MEMORY TESTERS BOARD TESTERS / SCANNERS

The TOSHIBA TLP3130 Mini-flat photorelay is a small-outline photorelay, suitable for surface-mount assembly. The TLP3130 consists of a GaAs infrared-emitting diode optically coupled to a photo-MOS FET and housed in a 4-pin package.

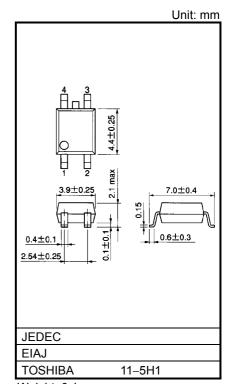
Its characteristics also include low OFF-state current and low output pin capacitance, enabling it to be used in high-frequency measuring instruments.

FEATURES

- 4 pin SOP (2.54SOP4)
- : 2.1 mm high, 2.54 mm pitch
- 1-Form-A
- Peak Off-State Voltage : 20 V (MIN.)
- Trigger LED Current : 4 mA (MAX.)
 - : 160 mA (MAX.)
- On-State Resistance $: 8 \Omega$
- Output Capacitance
- Isolation Voltage

• On-State Current

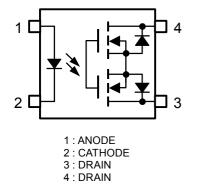
- : 8 Ω (MAX.), 5 Ω (TYP.)
 : 2.5 pF (MAX.), 1.0 pF (TYP.)
- : 1500 Vrms (MIN.)

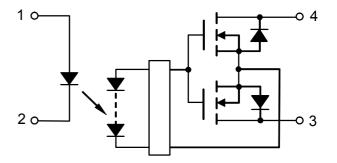


Weight: 0.1 g

PIN CONFIGURATION (TOP VIEW)

SCHEMATIC





MAXIMUM RATINGS (Ta = 25°C)

	CHARACTERISTIC	SYMBOL	RATING	UNIT
	Forward Current	١ _F	50	mA
D	Forward Current Derating (Ta \ge 25°C)	∆I _F /°C	-0.5	mA/°C
Ц	Reverse Voltage	V _R	5	V
	Junction Temperature	Tj	125	°C
DETECTOR	Off-State Output Terminal Voltage	V _{OFF}	20	V
	On-State Current	I _{ON}	160	mA
	On-State Current Derating (Ta \ge 25°C)	∆l _{ON} /°C	-1.6	mA/°C
	Junction Temperature	Tj	125	°C
Stora	ge Temperature Range	T _{stg}	-40~125	°C
Opera	ating Temperature Range	T _{opr}	-20~85	°C
Lead	Soldering Temperature (10 s)	T _{sol}	260	°C
Isolat	ion Voltage (AC, 1 minute, R.H. \leq 60%) (NOTE1)	BVS	1500	Vrms

(NOTE1): Device considered a two-terminal device : Pins 1 and, 2 shorted together, and pins 3 and 4 shorted together.

CAUTION

This device is sensitive to electrostatic discharge. When using this device, please ensure that all tools and equipment are earthed.

RECOMMENDED OPERATING CONDITIONS

CHARACTERISTIC	SYMBOL	MIN.	TYP.	MAX.	UNIT
Supply Voltage	V _{DD}		_	20	V
Forward Current	١ _F	10	_	30	mA
On-State Current	I _{ON}	_	_	160	mA
Operating Temperature	T _{opr}	25	_	60	°C

INDIVIDUAL ELECTRICAL CHARACTERISTICS (Ta = 25° C)

	CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
	Forward Voltage	V _F	I _F = 10 mA	1.0	1.15	1.3	V
LED	Reverse Current	I _R	$V_R = 5 V$			10	μA
	Capacitance	CT	V = 0, f = 1 MHz		15		pF
DETECTOR	Off-State Current	IOFF	V _{OFF} = 20 V, Ta = 50°C			1000	pА
DETE	Capacitance	C _{OFF}	V = 0, f = 100 MHz, t < 1 s		1.0	2.5	pF

COUPLED ELECTRICAL CHARACTERISTICS (Ta = 25°C)

CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Trigger LED Current	I _{FT}	I _{ON} = 100 mA	_	_	4	mA
Return LED Current	I _{FC}	I _{OFF} = 10 μA	0.2	0.75	_	mA
On-State Resistance	R _{ON}	I _{ON} = 100 mA, I _F = 5 mA, t < 1 s		5	8	Ω

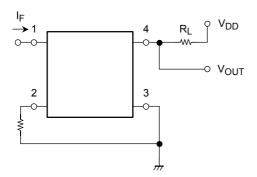
ISOLATION CHARACTERISTICS (Ta = 25°C)

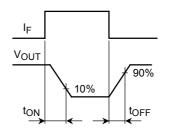
CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Capacitance Input to Output	CS	$V_{S} = 0 V$, f = 1 MHz	_	0.8	_	pF
Isolation Resistance	R _S	$V_S = 500 \text{ V}, \text{ R.H.} \leq 60\%$	5×10^{10}	10 ¹⁴	_	Ω
		AC, 1 minute	1500		_	Vrms
Isolation Voltage	BVS	AC, 1 second (in oil)	_	3000	_	VIIIS
		DC, 1 minute (in oil)		3000	_	Vdc

SWITCHING CHARACTERISTICS (Ta = 25°C)

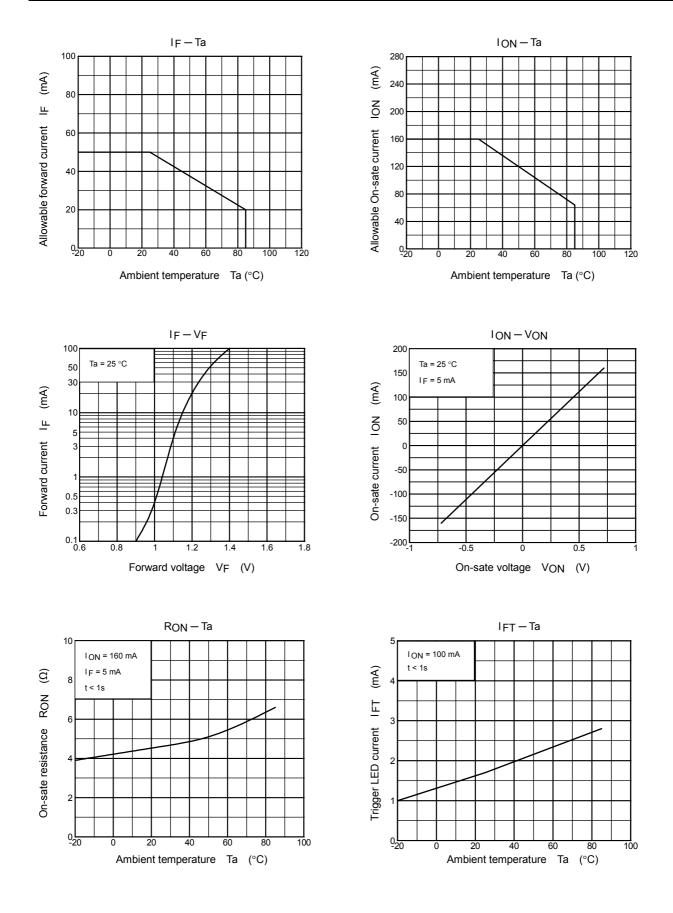
CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Turn-on Time	t _{ON}	R _L = 200 Ω (NOTE 2)	_	_	500	
Turn-off Time	tOFF	V _{DD} = 10 V, I _F = 10 mA		—	500	μS

(NOTE 2) : SWITCHING TIME TEST CIRCUIT

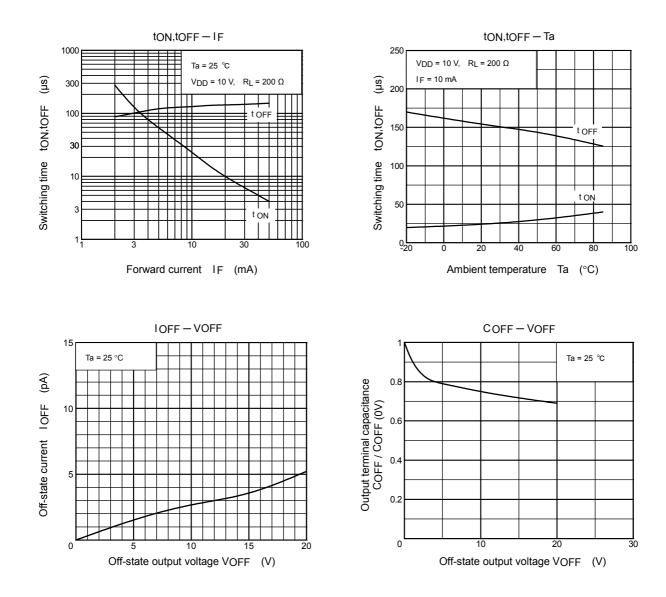




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system, and to avoid situations in which a malfunction or failure of such TOSHIBA products could cause loss of human life,
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In developing your designs, please ensure that TOSHIBA products are used within specified operating ranges as set forth in the most recent TOSHIBA products specifications. Also, please keep in mind the precautions and conditions set forth in the "Handling Guide for Semiconductor Devices," or "TOSHIBA Semiconductor Reliability Handbook" etc..

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